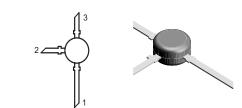


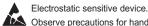


Silicon PNP Planar RF Transistor

Features

- High cross modulation performance
- High power gain
- · Low noise
- · High reverse attenuation
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC





Observe precautions for handling.

Applications

UHF/VHF uncontrolled prestages with low noise and low modulation.

Mechanical Data Case: TO-50 Plastic case

Weight: approx. 111 mg

Marking: BF970

Pinning: 1 = Collector, 2 = Base, 3 = Emitter

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Collector-base voltage		- V _{CBO}	20	V
Collector-emitter voltage		- V _{CEO}	20	V
Emitter-base voltage		- V _{EBO}	3	V
Collector current		- I _C	50	mA
Total power dissipation	T _{amb} ≤ 60 °C	P _{tot}	300	mW
Junction temperature		Tj	150	°C
Storage temperature range		T _{stg}	- 55 to + 150	°C

Maximum Thermal Resistance

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	1)	R_{thJA}	300	K/W

 $^{^{1)}}$ on glass fibre printed board (40 x 25 x 1.5) mm 3 plated with 35 μ m Cu

Electrical DC Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector cut-off current	- V _{CE} = 20 V, V _{BE} = 0	- I _{CES}			100	μΑ
Collector-base cut-off current	- V _{CB} = 15 V, I _E = 0	- I _{CBO}			100	nA
Emitter-base cut-off current	- V _{EB} = 3 V, I _C = 0	- I _{EBO}			10	μΑ
Collector-emitter breakdown voltage	- I _C = 1 mA, I _B = 0	- V _{(BR)CEO}	20			V
DC forward current transfer ratio	$- V_{CE} = 10 \text{ V}, - I_{C} = 10 \text{ mA}$	h _{FE}	20	50	90	

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Electrical AC Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Transition frequency	- V _{CE} = 10 V, - I _C = 10 mA, f = 300 MHz	f _T		1750		MHz
	$- V_{CE} = 10 \text{ V}, - I_{C} = 30 \text{ mA},$ f = 300 MHz	f _T		1300		MHz
Collector-base capacitance	- V _{CB} = 10 V, f = 100 MHz	C _{cb}		0.6		pF
Noise figure	- V_{CE} = 10 V, - I_{C} = 10 mA, Z_{S} = 50 Ω, f = 800 MHz	F		3.4	4.2	dB
Power gain	$ \begin{split} & \text{- V}_{\text{CE}} = \text{10 V, - I}_{\text{C}} = \text{10 mA,} \\ & Z_{\text{S}} = \text{50 } \Omega, Z_{\text{L}} = \text{500 } \Omega, \\ & \text{f} = \text{800 MHz} \end{split} $	G _{pb}		16		dB
Collector current for G _{pbmax}	- V_{CE} = 10 V, Z_{L} = 500 Ω, f = 800 MHz	- I _C		10		mA

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

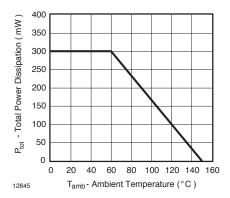


Figure 1. Total Power Dissipation vs. Ambient Temperature

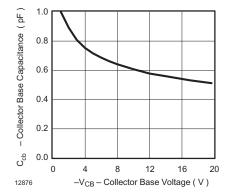


Figure 3. Collector Base Capacitance vs. Collector Base Voltage

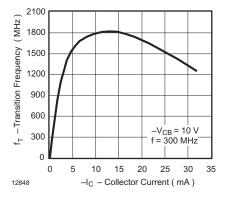
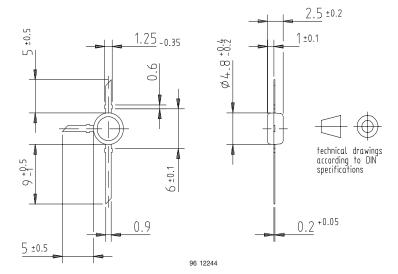


Figure 2. Transition Frequency vs. Collector Current





Package Dimensions in mm



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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